

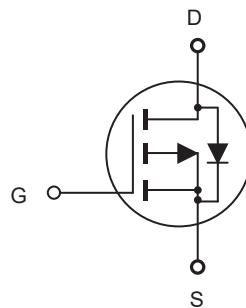


CED15P15A/CEU15P15A

P-Channel Enhancement Mode Field Effect Transistor

FEATURES

- -150V, -12.6A, $R_{DS(ON)} = 190m\Omega$ @ $V_{GS} = -10V$.
- Super high dense cell design for extremely low $R_{DS(ON)}$.
- High power and current handing capability.
- Pb-free lead plating ; RoHS compliant.
- Halogen Free.
- TO-251 & TO-252 package.



ABSOLUTE MAXIMUM RATINGS $T_C = 25^\circ C$ unless otherwise noted

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	-150	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous @ $T_C = 25^\circ C$ @ $T_C = 100^\circ C$	I_D	-12.6 -8	A
Drain Current-Pulsed ^a	I_{DM}	-50.4	A
Maximum Power Dissipation @ $T_C = 25^\circ C$ - Derate above 25°C	P_D	54 0.43	W W/°C
Single Pulsed Avalanche Energy ^d	E_{AS}	148	mJ
Single Pulsed Avalanche Current ^d	I_{AS}	7.7	A
Operating and Store Temperature Range	T_J, T_{stg}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Limit	Units
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.3	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	50	°C/W



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Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-150			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = -150\text{V}, V_{\text{GS}} = 0\text{V}$			-1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	$V_{\text{GS}} = 20\text{V}, V_{\text{DS}} = 0\text{V}$			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	$V_{\text{GS}} = -20\text{V}, V_{\text{DS}} = 0\text{V}$			-100	nA
On Characteristics^b						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{GS}} = V_{\text{DS}}, I_D = -250\mu\text{A}$	-2		-4	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -10\text{V}, I_D = -7.5\text{A}$		153	190	$\text{m}\Omega$
Gate Input Resistance	R_g	f=1MHz,open Drain		3.7		Ω
Dynamic Characteristics^c						
Input Capacitance	C_{iss}	$V_{\text{DS}} = -25\text{V}, V_{\text{GS}} = 0\text{V}, f = 1.0 \text{ MHz}$		2340		pF
Output Capacitance	C_{oss}			125		pF
Reverse Transfer Capacitance	C_{rss}			95		pF
Switching Characteristics^c						
Turn-On Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -75\text{V}, I_D = -7.5\text{A}, V_{\text{GS}} = -10\text{V}, R_{\text{GEN}} = 10\Omega$		22		ns
Turn-On Rise Time	t_r			14		ns
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$			66		ns
Turn-Off Fall Time	t_f			22		ns
Total Gate Charge	Q_g	$V_{\text{DS}} = -120\text{V}, I_D = -7.5\text{A}, V_{\text{GS}} = -10\text{V}$		45		nC
Gate-Source Charge	Q_{gs}			8		nC
Gate-Drain Charge	Q_{gd}			15		nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Current	I_S				-12.6	A
Drain-Source Diode Forward Voltage ^b	V_{SD}	$V_{\text{GS}} = 0\text{V}, I_S = -12\text{A}$			-1.2	V
Notes :						
a.Repetitive Rating : Pulse width limited by maximum junction temperature .						
b.Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.						
c.Guaranteed by design, not subject to production testing.						
d.L = 5mH, $I_{\text{AS}} = 7.7\text{A}$, $V_{\text{DD}} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$.						

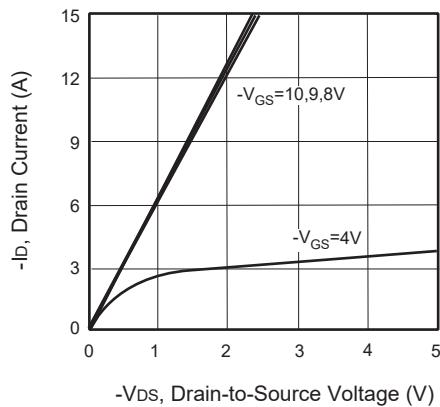


Figure 1. Output Characteristics

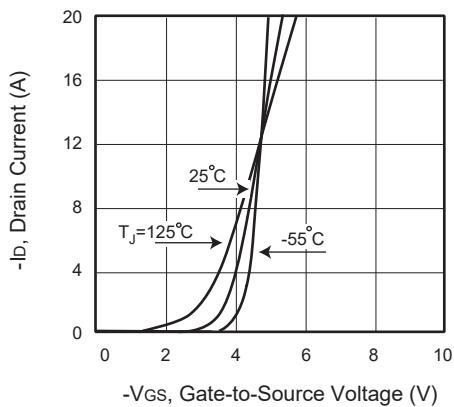


Figure 2. Transfer Characteristics

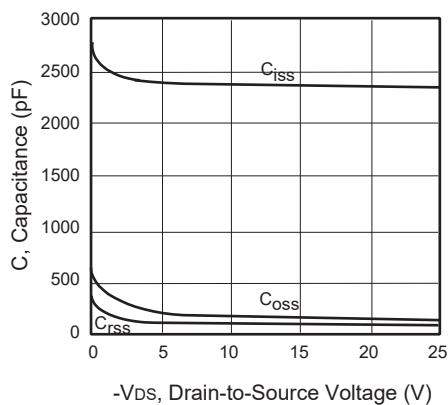


Figure 3. Capacitance

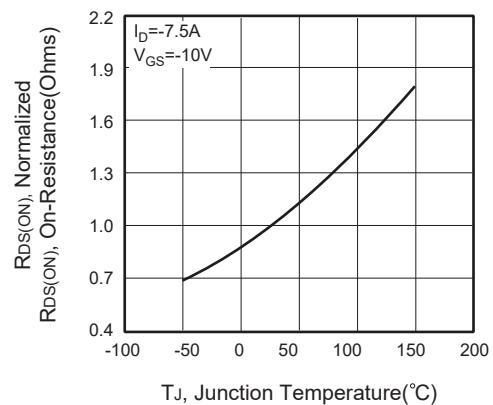


Figure 4. On-Resistance Variation with Temperature

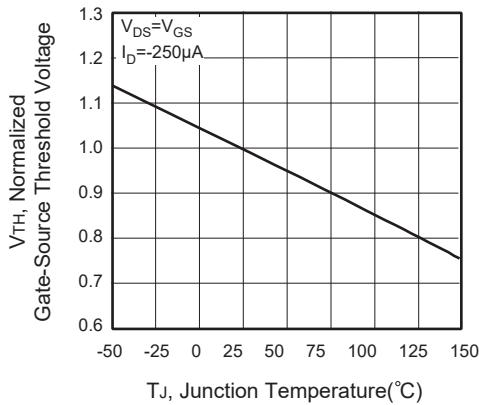


Figure 5. Gate Threshold Variation with Temperature

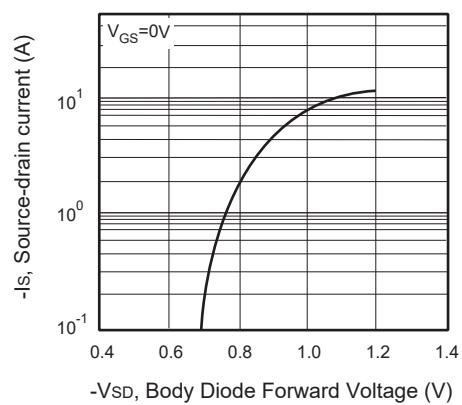


Figure 6. Body Diode Forward Voltage Variation with Source Current



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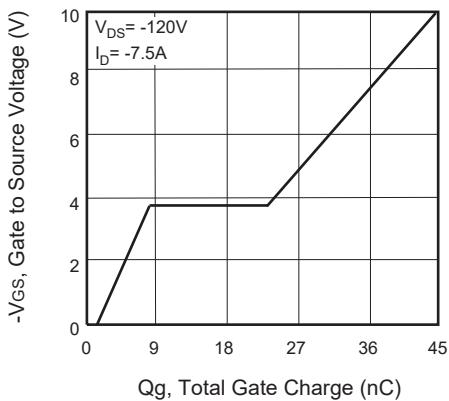


Figure 7. Gate Charge

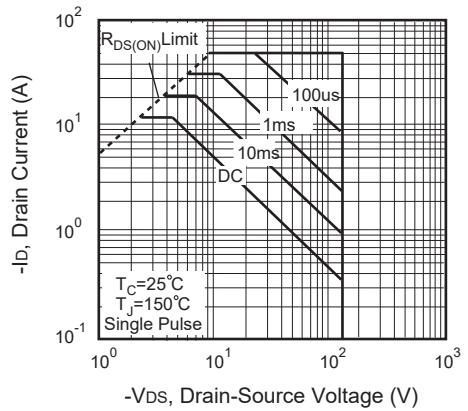


Figure 8. Maximum Safe
Operating Area

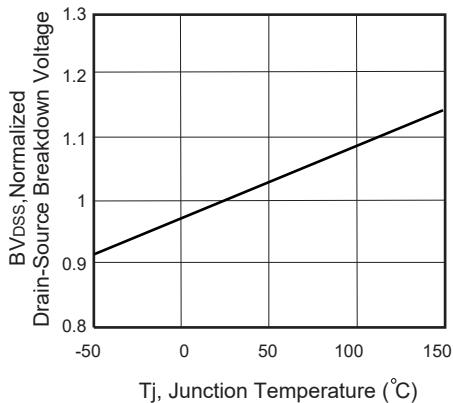


Figure 9. Breakdown Voltage Variation
VS Temperature

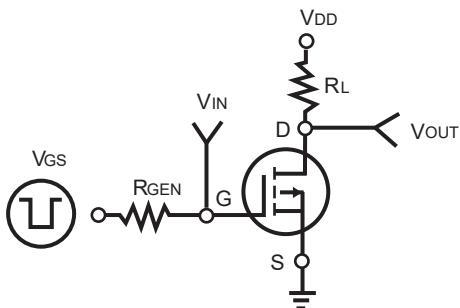


Figure 10. Switching Test Circuit

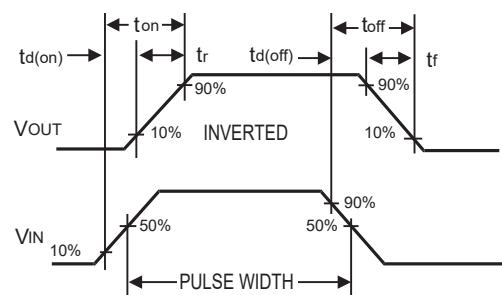


Figure 11. Switching Waveforms



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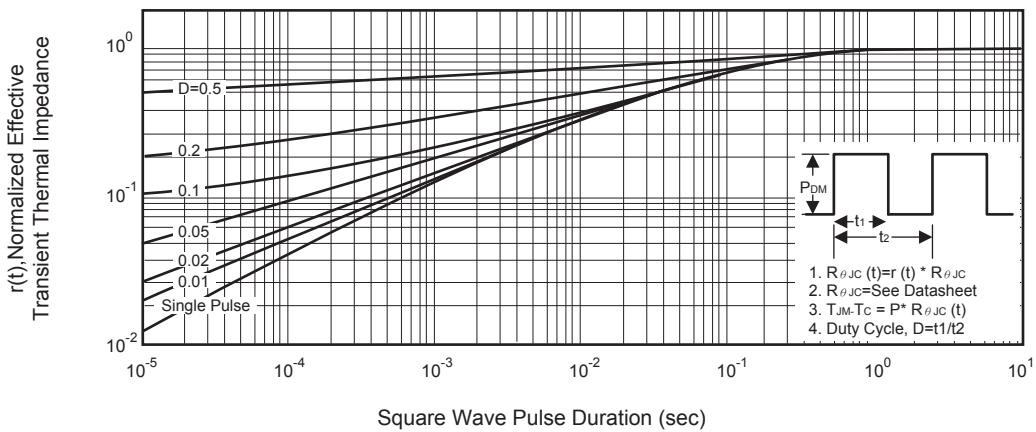


Figure 12. Normalized Thermal Transient Impedance Curve